

150mA Small Dual LDO Regulator with ON/OFF Switch

■ GENERAL DESCRIPTION

The XC6420 series is a small dual CMOS LDO regulator with 2-channel 150mA outputs. The series features high speed, high accuracy, high ripple rejection and low dropout voltage. The series is capable of high density board installation by the small package of two low on-resistance regulators. Each output voltage is internally set in a range from 1.2V to 3.6V in increments of 0.05V with $\pm 2\%$ accuracy.

The EN function controls the two regulators on/off independently. In the stand-by mode, the electric charge at the output capacitor C_L is discharged via the internal switch and as a result the V_{OUT} pin quickly returns to the V_{SS} level.

The series is also compatible with low ESR ceramic capacitors. The high level of output stability is maintained even during frequent load fluctuations, due to the excellent transient response performance. The two regulators are completely isolated so that a cross talk during load fluctuations is minimized.

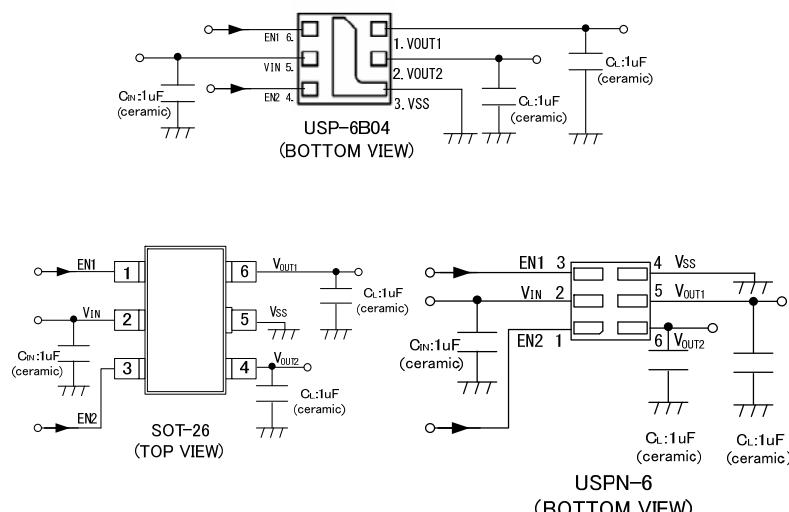
■ APPLICATIONS

- Smart phones / Mobile phones
- Portable game consoles
- Digital audio equipments
- Digital still cameras / Camcorders

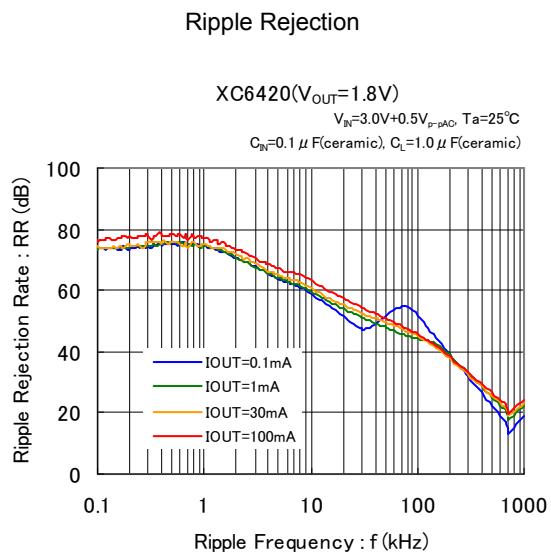
■ FEATURES

Maximum Output Current	: 150mA
Operating Voltage Range	: 1.6V~5.5V
Output Voltage	: 1.2V~3.6V ($\pm 2\%$) 0.05V increments
Dropout Voltage	: 190mV @ $I_{OUT}=150mA$ ($V_{OUT}=3.3V$)
Low Power Consumption	: 55 μA / ch (TYP.)
Stand-by Current	: 0.1 μA
Ripple Rejection	: 75dB@1kHz
EN Function	: Active High
Protection Circuit	: CL High Speed Auto Discharge Current Limit 250mA (TYP.) Short Circuit 50mA (TYP.)
Output Capacitor	: 1.0 μF Ceramic Capacitor
Operating Ambient Temperature	: -40°C~+85°C
Packages	: SOT-26 USPN-6 USP-6B04
Environmentally Friendly	: EU RoHS Compliant, Pb Free

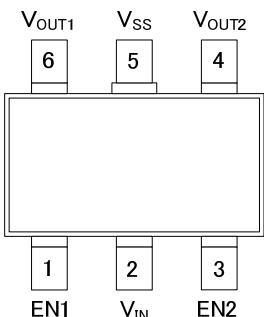
■ TYPICAL APPLICATION CIRCUITS



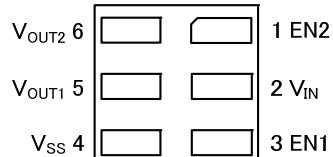
■ TYPICAL PERFORMANCE CHARACTERISTICS



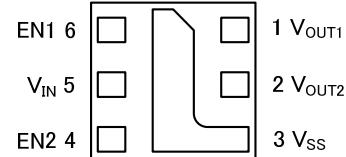
■PIN CONFIGURATION



SOT-26
(TOP VIEW)



USPN-6
(BOTTOM VIEW)



USP-6B04
(BOTTOM VIEW)

■PIN ASSIGNMENT

PIN NUMBER			PIN NAME	FUNCTIONS
SOT-26	USPN-6	USP-6B04		
1	3	6	EN1	ON/OFF Control 1
2	2	5	V _{IN}	Power Input
3	1	4	EN2	ON/OFF Control 2
4	6	2	V _{OUT2}	Output 2
5	4	3	V _{SS}	Ground
6	5	1	V _{OUT1}	Output 1

■PIN FUNCTION ASSIGNMENT

PIN NAME	SIGNAL	STATUS
EN	L	Stand-by
	H	Active
	OPEN	Stand-by ※

H = High Level , L = Low Level

※An internal pull-down resistor maintains the EN pin voltage to be low.

■ PRODUCT CLASSIFICATION

● Ordering Information

XC6420①②③④⑤⑥-⑦^(*)1)

DESIGNATOR	ITEM	SYMBOL	DESCRIPTION
①②	Type	AB	Refer to Selection Guide
③④	Output Voltage	01~	See the chart below
⑤⑥-⑦ ^(*)1)	Packages (Order Unit)	MR-G	SOT-26 (3,000pcs/Reel)
		7R-G	USPN-6 (5,000pcs/Reel)
		DR-G	USP-6B04 (5,000pcs/Reel)

(*)1) The “-G” suffix denotes Halogen and Antimony free as well as being fully EU RoHS compliant.

Selection Guide

TYPE	CURRENT LIMITTER	EN PULL-DOWN RESISTOR	C _L DISCHARGE
AB	Yes	Yes	Yes

XC6420 Series

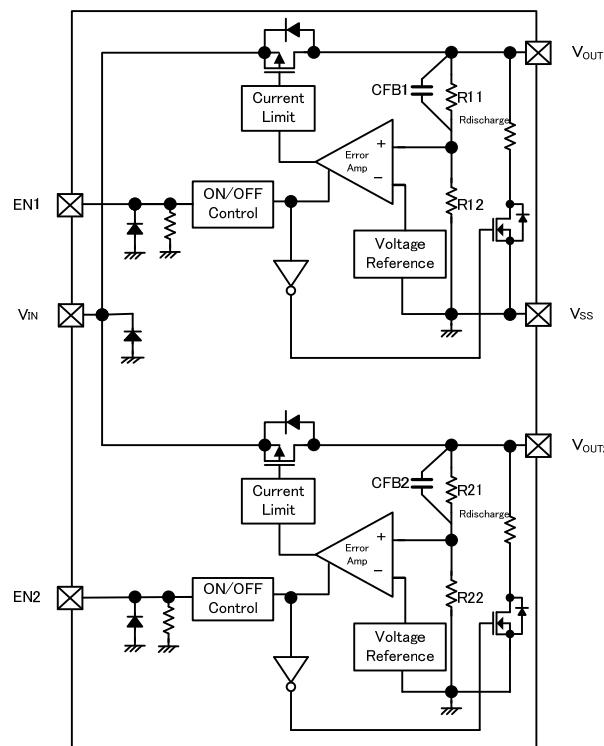
DESIGNATOR ③④

③④	VR1(V)	VR2(V)	③④	VR1(V)	VR2(V)	③④	VR1(V)	VR2(V)
01	1.20	1.20	34	2.80	3.00	67	2.75	2.75
02	1.20	1.50	35	2.80	3.30	68	2.50	1.80
03	1.20	2.50	36	1.20	3.60	69	1.80	1.35
04	1.20	2.85	37	3.60	1.20	70	1.30	2.30
05	1.20	3.00	38	1.20	2.80	71	3.10	1.80
06	1.20	3.30	39	3.30	2.00	72	3.00	2.60
07	1.50	1.50	40	3.00	3.30	73	1.80	2.90
08	1.50	1.80	41	3.30	3.30	74	3.30	2.20
09	1.50	2.50	42	1.30	1.50	75	1.20	1.40
10	1.50	2.85	43	2.60	2.80	76	1.90	3.00
11	1.50	3.00	44	3.10	3.30	77	2.00	2.70
12	1.50	3.30	45	1.50	2.60	78	2.80	1.80
13	1.80	1.80	46	2.60	3.30			
14	1.80	2.50	47	3.40	3.40			
15	2.85	2.85	48	2.85	2.60			
16	1.80	2.85	49	3.30	1.80			
17	1.80	3.00	50	1.80	1.20			
18	3.00	1.80	51	3.10	3.10			
19	1.80	3.30	52	1.50	3.10			
20	2.50	2.50	53	3.30	2.80			
21	2.50	2.80	54	3.00	2.80			
22	2.50	2.85	55	3.30	3.00			
23	3.30	1.50	56	3.60	3.60			
24	2.50	3.00	57	3.30	3.10			
25	2.50	3.30	58	3.10	3.00			
26	2.85	3.00	59	3.10	2.90			
27	2.85	3.30	60	3.10	2.50			
28	3.00	3.00	61	3.00	2.90			
29	1.20	1.80	62	3.00	2.50			
30	1.30	2.80	63	1.80	1.90			
31	1.50	2.80	64	1.80	1.85			
32	1.80	2.80	65	1.70	1.70			
33	2.80	2.80	66	2.70	2.70			

For other output voltage combinations, please contact your local Torex sales office or representative.

■BLOCK DIAGRAMS

XC6420ABxxxxseries



* Diodes inside the circuits are ESD protection diodes and parasitic diodes.

■ABSOLUTE MAXIMUM RATINGS

PARAMETER	SYMBOL	RATINGS	UNITS
Input Voltage	V _{IN}	V _{SS} -0.3~+7.0	V
Output Current	I _{OUT1} +I _{OUT2}	600 (*1)	mA
Output Voltage 1 / Output Voltage2	V _{OUT1} /V _{OUT2}	V _{SS} -0.3~V _{IN} +0.3	V
EN1/EN2 Input Voltage	V _{EN1} /V _{EN2}	V _{SS} -0.3~+7.0	V
Power Dissipation	SOT-26	250	mW
		600 (PCB mounted) (*2)	
	USPN-6	100	
		600 (PCB mounted) (*2)	
	USP-6B04	600 (PCB mounted)(*2)	
Operating Ambient Temperature	T _{opr}	-40~+85	°C
Storage Temperature	T _{tstg}	-55~+125	°C

(*1) Please use within the range of Pd > { (V_{IN}-V_{OUT1})×I_{OUT1} + (V_{IN}-V_{OUT2})×I_{OUT2} }

(*2) This is a reference data taken by using the test board. Please refer to 22~24 for detail information of test condition.

■ ELECTRICAL CHARACTERISTICS

● XC6420 series

Regulator1, Regulator2

T_a=25°C

PARAMETER	SYMBOL	CONDITIONS	MIN.	TYP.	MAX.	UNITS	CIRCUITS
Output Voltage	V _{OUT(E)} (*2)	V _{EN} =V _{IN} , I _{OUT} =10mA	V _{OUT(T)} ×0.98 (*3)	V _{OUT(T)} (*4)	V _{OUT(T)} ×1.02 (*3)	V	①
Maximum Output Current	I _{OUTMAX}	V _{EN} =V _{IN}	150	-	-	mA	①
Load Regulation	ΔV _{OUT}	V _{EN} =V _{IN} 0.1mA≤I _{OUT} ≤150mA	-	25	45	mV	①
Dropout Voltage	V _{dif}	I _{OUT} =150mA, V _{EN} =V _{IN}	See "OUTPUT VOLTAGE CHART"			mV	①
Supply Current	I _{SS}	V _{EN} =V _{IN} I _{OUT} =0mA	-	55	105	μA	②
Stand-by Current	I _{STB}	V _{EN} =V _{SS}	-	0.01	0.1	μA	②
Line Regulation	ΔV _{OUT} / (ΔV _{IN} ·V _{OUT})	2.5V≤V _{IN} ≤5.0V (V _{OUT(T)} ≤2.0V) V _{EN} =V _{IN} , I _{OUT} =30mA	-	0.02	0.1	%/V	①
		V _{OUT(T)} +0.5V≤V _{IN} ≤5.5V (V _{OUT(T)} ≥2.05V) V _{EN} =V _{IN} , I _{OUT} =30mA					
Input Voltage	V _{IN}	-	1.6	-	5.5	V	①
Output Voltage Temperature Characteristics (R&D Value)	ΔV _{OUT} / (ΔT _{opr} ·V _{OUT})	V _{EN} =V _{IN} , I _{OUT} =10mA -40°C≤T _a ≤85°C	-	±100	-	ppm /°C	①
Power Supply Rejection Ratio	PSRR	V _{EN} =V _{IN} V _{IN} {V _{OUT(T)} +1.0}+0.5V _{p-pAC} I _{OUT} =30mA, f=1kHz	-	75	-	dB	③
Limit Current	I _{LIM}	V _{EN} =V _{IN}	150	250	-	mA	①
Short Current	I _{SHORT}	V _{EN} =V _{IN} V _{OUT} =V _{SS}	-	50	-	mA	①
EN"H"Level Voltage	V _{ENH}	-	1.0	-	5.5	V	①
EN"L"Level Voltage	V _{ENL}	-	-	-	0.3	V	①
EN"H"Level Current	I _{ENH}	V _{EN} =V _{IN} =5.5V	2.5	6.0	9.1	μA	①
EN"L"Level Current	I _{ENL}	V _{EN} =V _{SS}	-0.1	-	0.1	μA	①
C _L Discharge Resistor	R _{DCHG}	V _{IN} =5.5V, V _{EN} =V _{SS} V _{OUT} =2.0V	-	300	-	Ω	①

NOTE:

Unless otherwise stated, V_{IN}=V_{OUT(T)}+1V, I_{OUT}=1mA, C_{IN}=C_L=1.0 μF.

(*1) V_{OUT(E)}: Effective output voltage

(*2) Characteristics of the actual V_{OUT(E)} by setting output voltage is shown in the voltage chart.

(*3) V_{OUT(T)}: Nominal output voltage

(*4) V_{dif}={V_{IN1}-V_{OUT1}}

V_{IN1}: The input voltage when V_{OUT1} appears as input voltage is gradually decreased.

V_{OUT1}: A voltage equal to 98% of the output voltage whenever an amply stabilized I_{OUT}{V_{OUT(T)}+1.0V} is input.

(*5) Each channel is measured when the other channel is turned off (V_{EN}=V_{SS}).

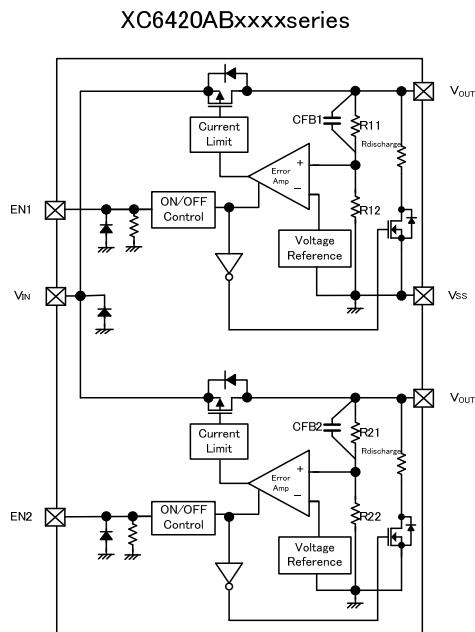
■OUTPUT VOLTAGE CHART

NOMINAL OUTPUT VOLTAGE (V)	OUTPUT VOLTAGE (V)		DROPOUT VOLTAGE (mV)	
V _{OUT(T)}	V _{OUT(E)}		V _{dif}	
	MIN.	MAX.	TYP.	MAX.
1.200	1.176	1.224	560	710
1.250	1.225	1.275		
1.300	1.274	1.326	530	600
1.350	1.323	1.377		
1.400	1.372	1.428	460	520
1.450	1.421	1.479		
1.500	1.470	1.530		
1.550	1.519	1.581		
1.600	1.568	1.632		
1.650	1.617	1.683	380	470
1.700	1.666	1.734		
1.750	1.715	1.785		
1.800	1.764	1.836		
1.850	1.813	1.887		
1.900	1.862	1.938	300	450
1.950	1.911	1.989		
2.000	1.960	2.040		
2.050	2.009	2.091		
2.100	2.058	2.142		
2.150	2.107	2.193	280	390
2.200	2.156	2.244		
2.250	2.205	2.295		
2.300	2.254	2.346		
2.350	2.303	2.397		
2.400	2.352	2.448		

NOMINAL OUTPUT VOLTAGE (V)	OUTPUT VOLTAGE (V)		DROPOUT VOLTAGE (mV)	
V _{OUT(T)}	V _{OUT(E)}		V _{dif}	
	MIN.	MAX.	TYP.	MAX.
2.450	2.401	2.499	280	390
2.500	2.450	2.550	200	340
2.550	2.499	2.601		
2.600	2.548	2.652		
2.650	2.597	2.703		
2.700	2.646	2.754		
2.750	2.695	2.805		
2.800	2.744	2.856		
2.850	2.793	2.907		
2.900	2.842	2.958		
2.950	2.891	3.009	190	270
3.000	2.940	3.060		
3.050	2.989	3.111		
3.100	3.038	3.162		
3.150	3.087	3.213		
3.200	3.136	3.264		
3.250	3.185	3.315		
3.300	3.234	3.366		
3.350	3.283	3.417		
3.400	3.332	3.468		
3.450	3.381	3.519		
3.500	3.430	3.570		
3.550	3.479	3.621		
3.600	3.528	3.672		

■ OPERATIONAL EXPLANATION

The voltage divided by resistors Rx1 & Rx2 is compared with the internal reference voltage by the error amplifier. The P-channel MOSFET connected to the V_{OUT} pin is then driven by the subsequent output signal. The output voltage at the V_{OUT} pin is controlled & stabilized by a system of negative feedback. The current limit circuit and short protect circuit operate in relation to the level of output current. Further, the IC's internal circuitry can be shutdown via the EN pin's signal.



<Low ESR Capacitor>

The XC6420 needs an output capacitor (C_L) for phase compensation. In order to ensure the effectiveness of the phase compensation, we suggest that an output capacitor (C_L) is connected as close as possible to the output pin (V_{OUT}) and the V_{SS} pin. Please use an output capacitor with a capacitance value of at least 1.0 μ F. Also, please place 1.0 μ F input capacitor C_I between V_{IN} and V_{SS} pins for stabilizing input supply voltage.

<Current Limiter, Short-Circuit Protection>

The XC6420 includes a combination of a fixed current limiter circuit & a foldback circuit, which aid the operations of the current limiter and circuit protection. When the load current reaches the current limit level, the fixed current limiter circuit operates and output voltage drops. As a result of this drop in output voltage, the foldback circuit operates, output voltage drops further and output current decreases. When the output pin is shorted, a current of about 50mA flows.

<EN Pin>

The IC's internal circuitry can be shutdown via the signal from the EN pin with the XC6420 series. In shutdown mode, the series enables the electric charge at the output capacitor C_L to be discharged via the internal switch between V_{OUT} pin and V_{SS} pin, and as a result the V_{OUT} pin quickly returns to the V_{SS} level.

The EN pin is internally pulled down by a resistor. Please note that input current through a pull-down resistor exists.

<C_L Auto-Discharge Function>

XC6420 series can quickly discharge the electric charge at the output capacitor (C_L), when a low signal to the EN pin, which enables a whole IC circuit put into OFF state, is inputted via the N-channel transistor located between the V_{OUT} pin and the V_{SS} pin (cf. BLOCK DIAGRAM). The C_L discharge resistance is set to 300 Ω when V_{IN} is 5.5V (TYP.) and V_{OUT} is 2.0V (TYP.). Moreover, discharge time of the output capacitor (C_L) is set by the C_L auto-discharge resistance and the output capacitor (C_L). By setting time constant of a C_L auto-discharge resistance value [R_{DCHG}] and an output capacitor value (C_L) as τ ($\tau = C \times R$), the output voltage after discharge via the N channel transistor is calculated by the following formulas.

$$V = V_{OUT(E)} \times e^{-t/\tau}, \quad \text{or} \quad t = \tau \ln(V/V_{OUT(E)})$$

V : Output voltage after discharge, V_{OUT(E)} : Output voltage, t: Discharge time,

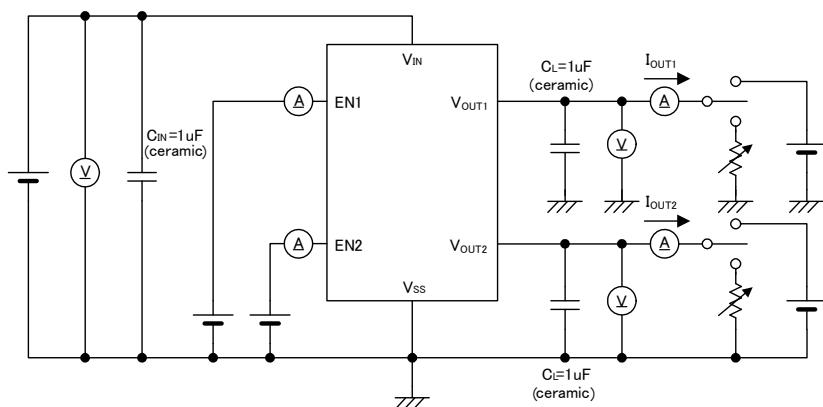
τ : C_L auto-discharge resistance R_{DCHG} × Output capacitor (C_L) value C

■NOTES ON USE

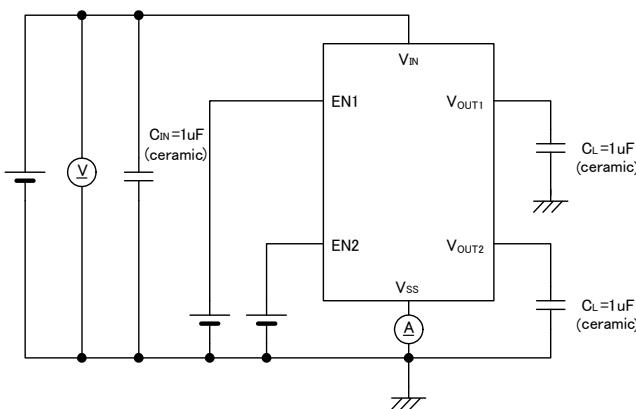
1. For temporary, transitional voltage drop or voltage rising phenomenon, the IC is liable to malfunction should the ratings be exceeded.
2. Torex places an importance on improving our products and its reliability.
However, by any possibility, we would request user fail-safe design and post-aging treatment on system or equipment.
3. Where wiring impedance is high, operations may become unstable due to the noise and/or phase lag depending on output current. Please strengthen V_{IN} and V_{SS} wiring in particular.
4. Please wire the input capacitor (C_{IN}) and the output capacitor (C_L) as short and close to the IC as possible.

■ TEST CIRCUITS

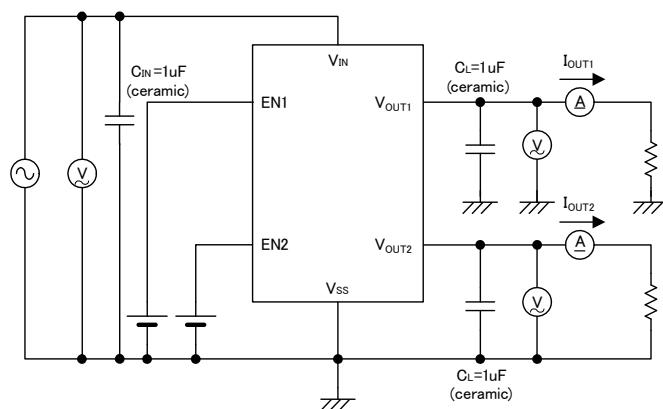
●Circuit ①



●Circuit ②



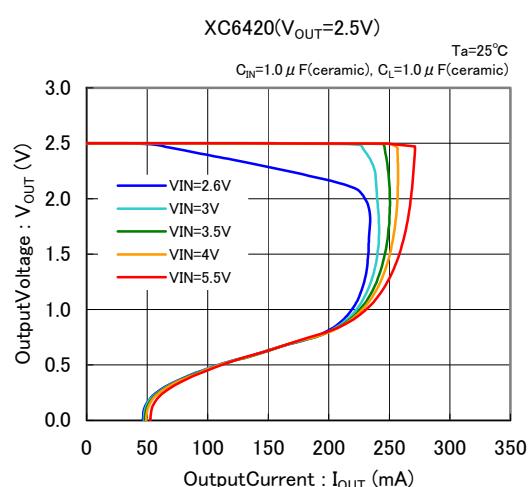
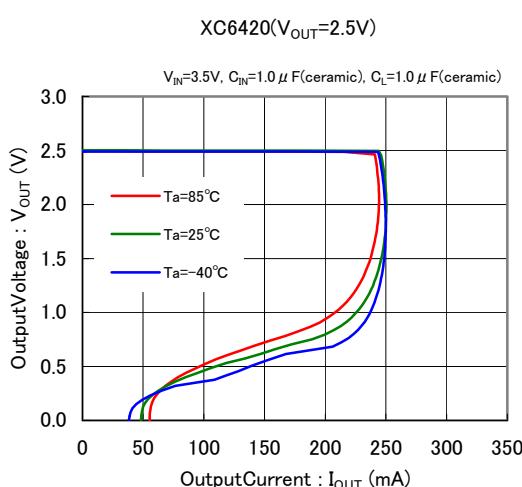
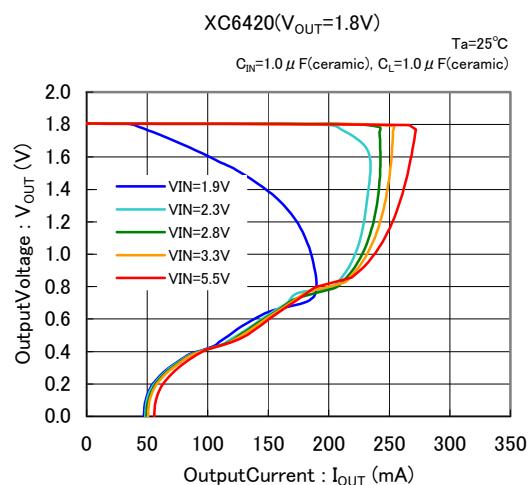
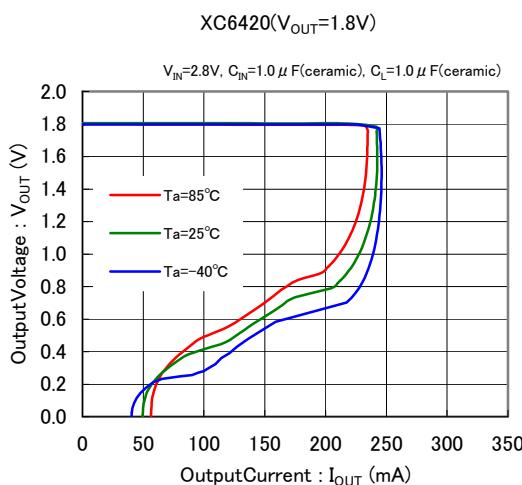
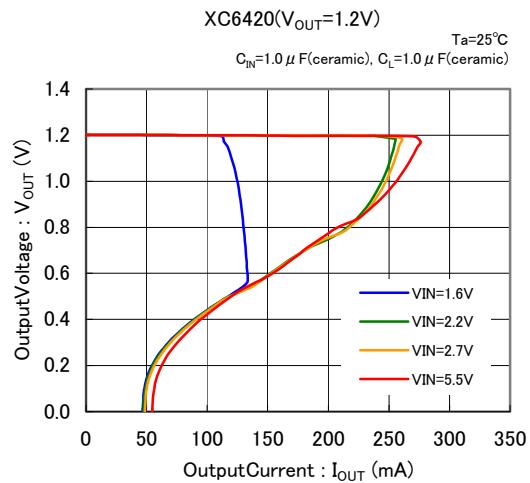
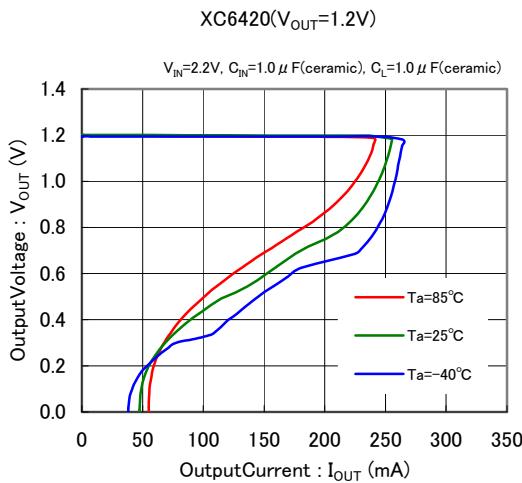
●Circuit ③



■ TYPICAL PERFORMANCE CHARACTERISTICS

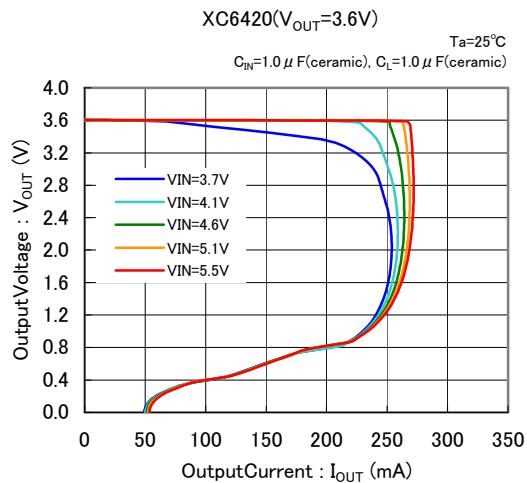
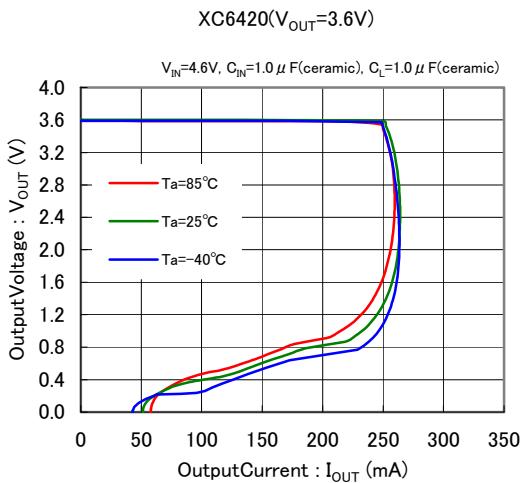
* EN Voltage condition: Unless otherwise stated, $V_{EN}=V_{IN}$.

(1) OutputVoltage vs. OutputCurrent

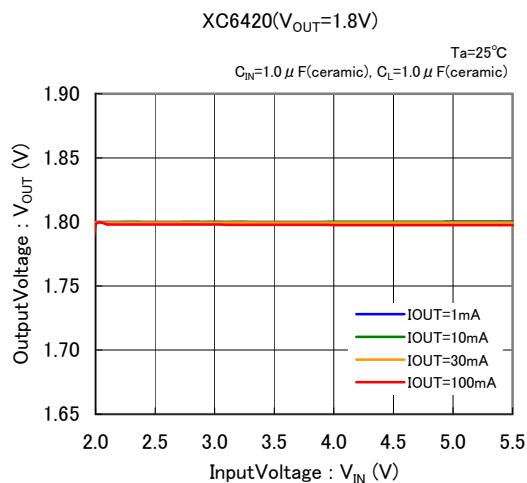
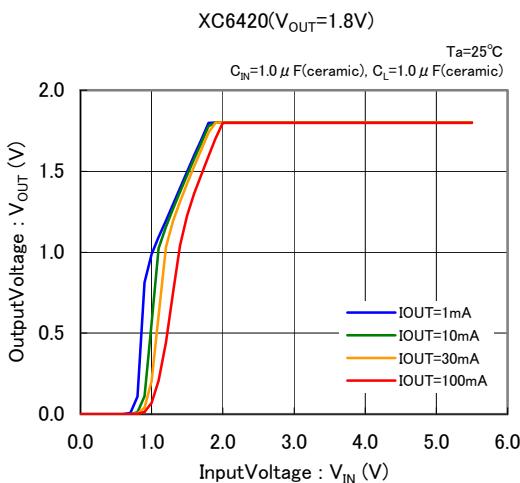
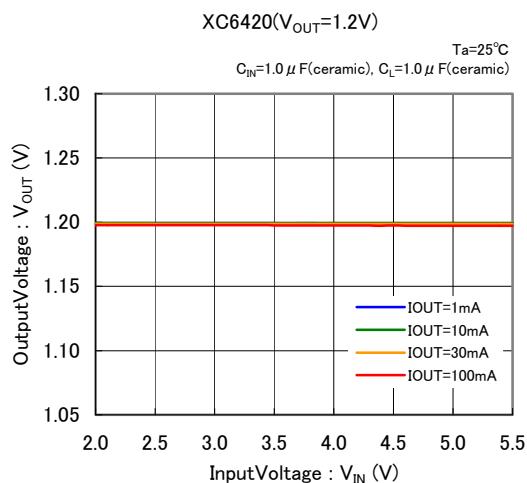
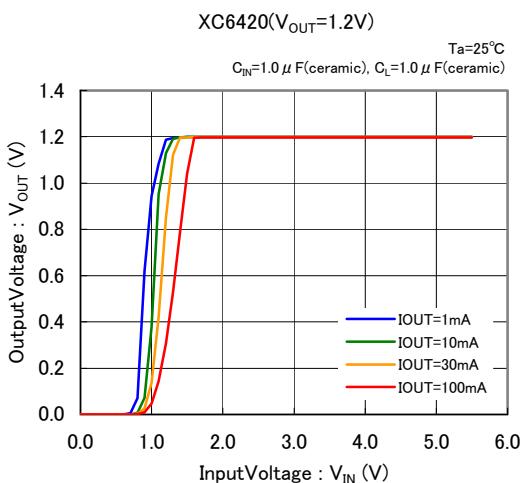


■ TYPICAL PERFORMANCE CHARACTERISTICS (Continued)

(1) Output Voltage vs. Output Current

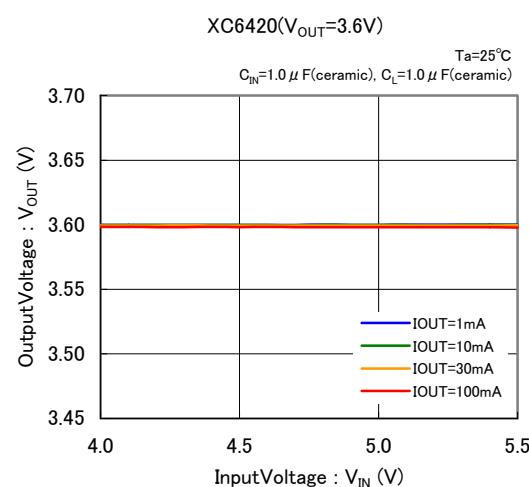
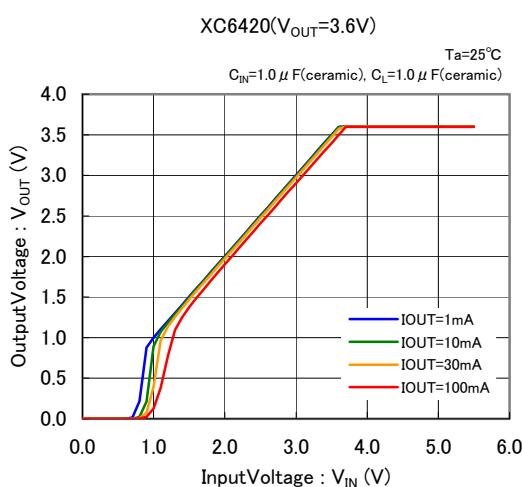
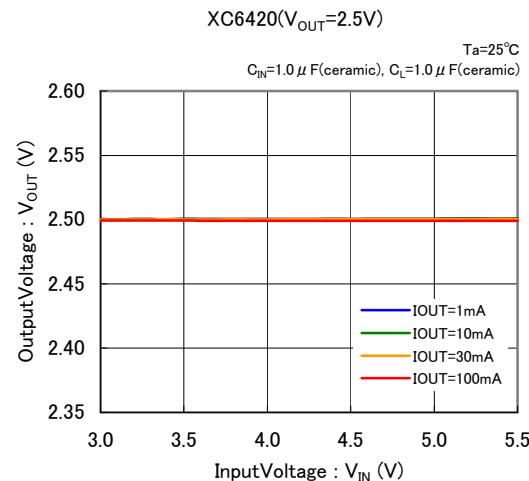
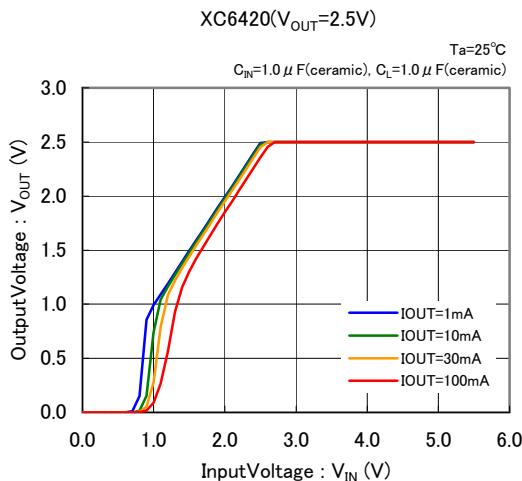


(2) Output Voltage vs. Input Voltage

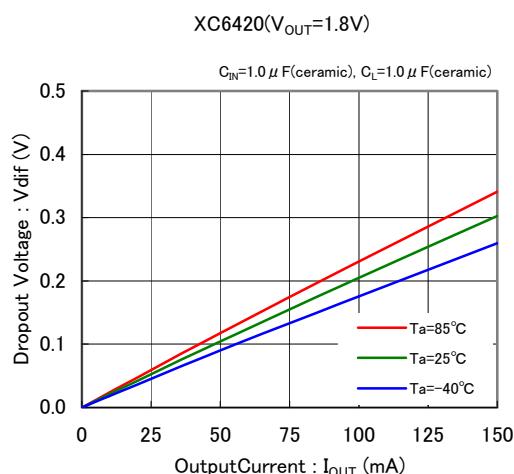
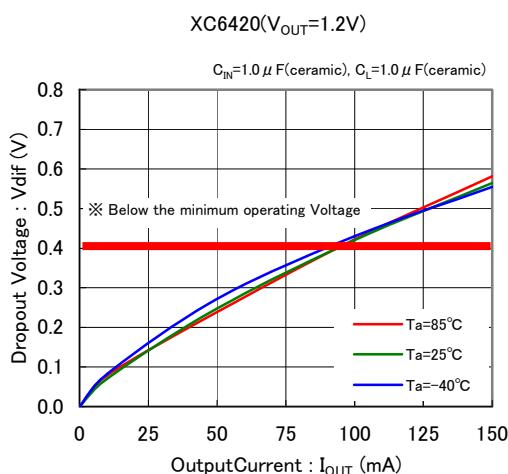


■ TYPICAL PERFORMANCE CHARACTERISTICS (Continued)

(2) Output Voltage vs. Input Voltage

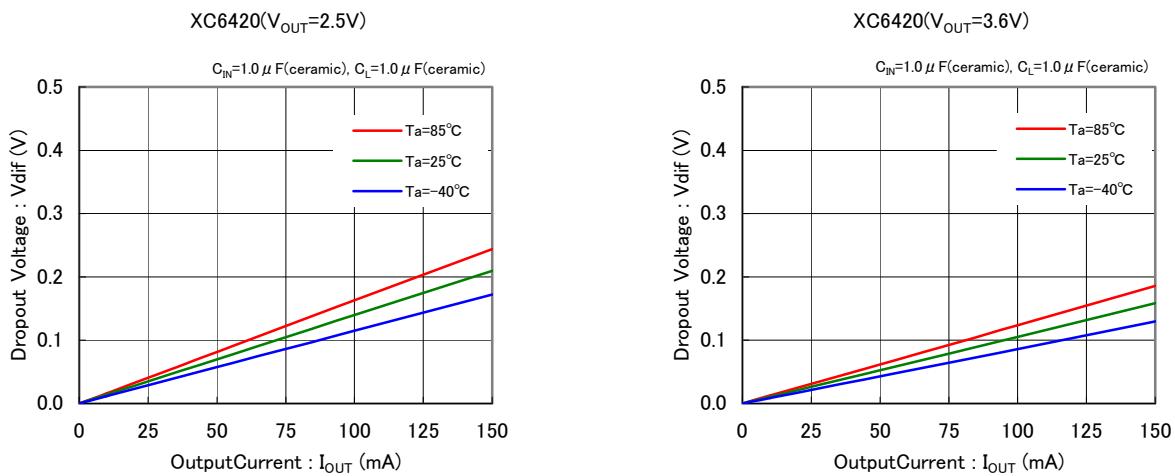


(3) Dropout Voltage vs. Output Current

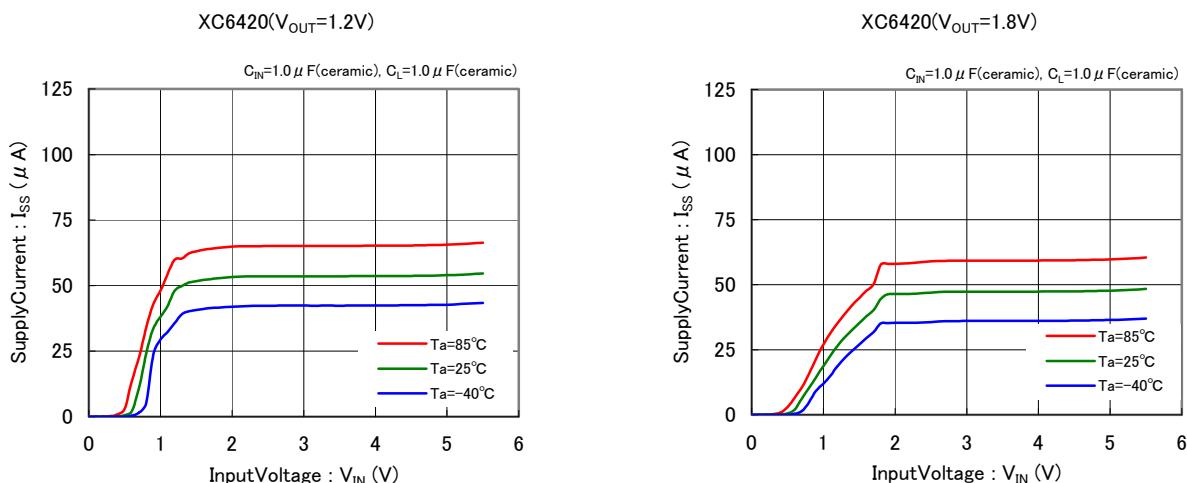


■ TYPICAL PERFORMANCE CHARACTERISTICS (Continued)

(3) Dropout Voltage vs. Output Current

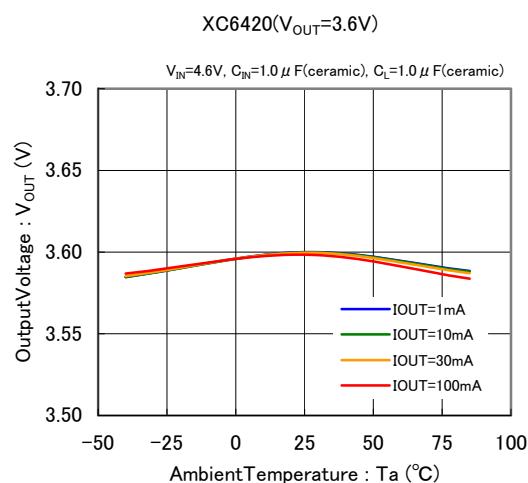
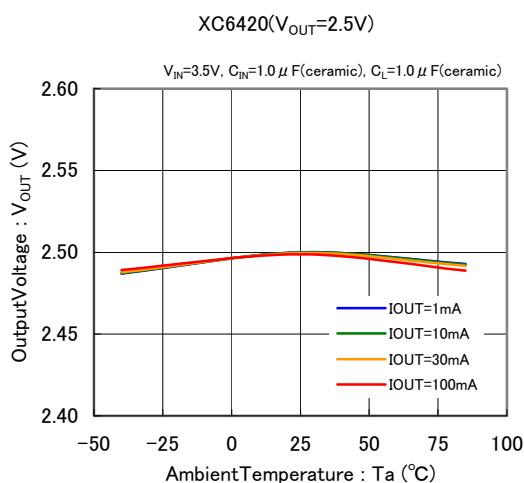
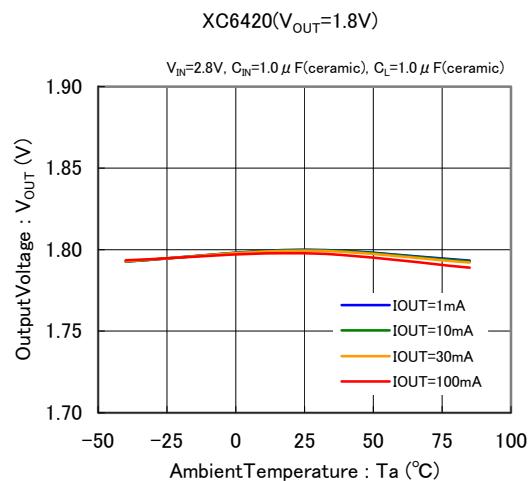
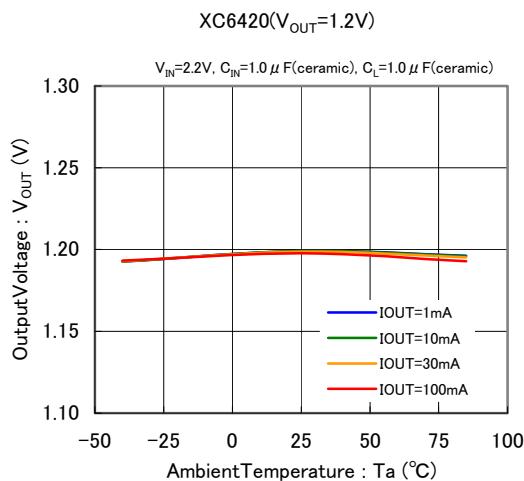


(4) Supply Current vs. Input Voltage

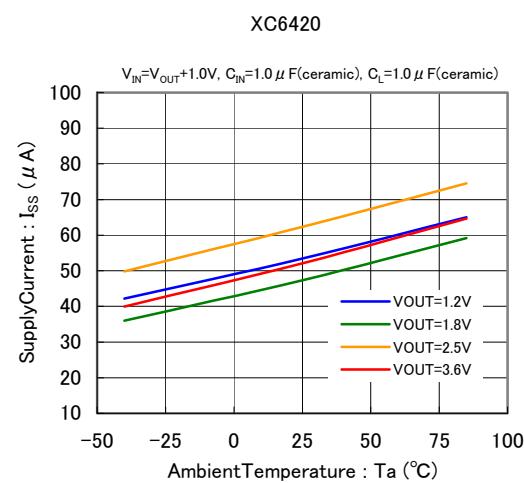


■ TYPICAL PERFORMANCE CHARACTERISTICS (Continued)

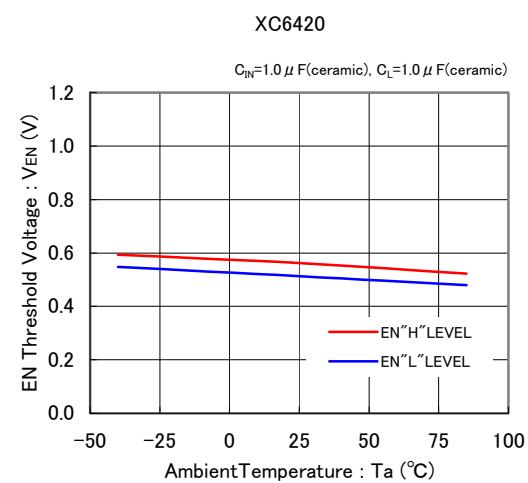
(5) Output Voltage vs. Ambient Temperature



(6) Supply Current vs. Ambient Temperature

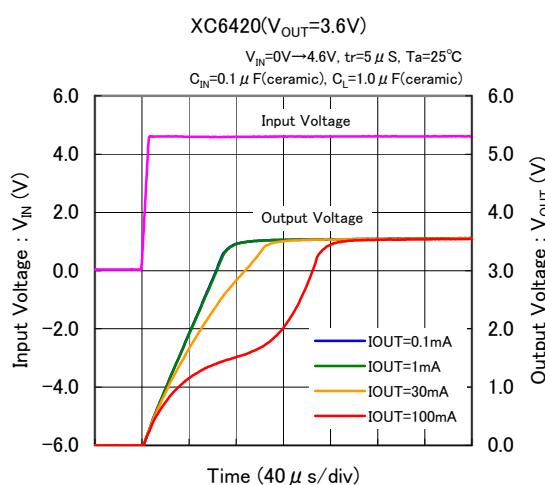
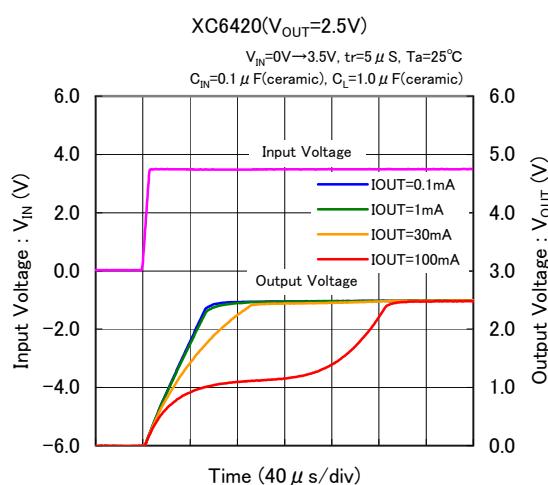
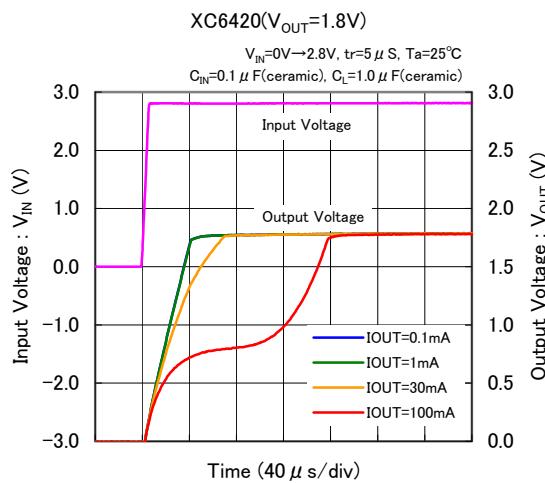
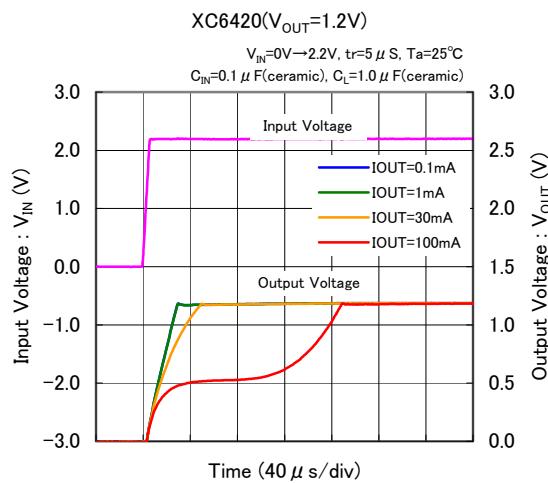


(7) EN Threshold Voltage vs. Ambient Temperature

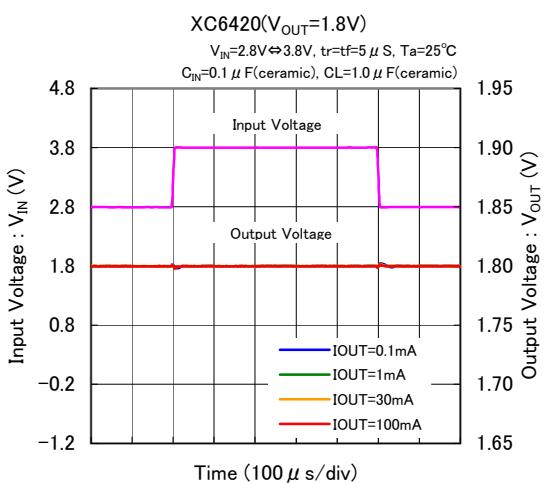
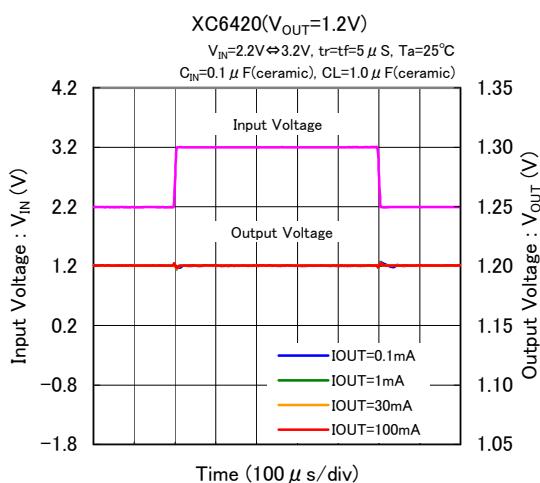


■ TYPICAL PERFORMANCE CHARACTERISTICS (Continued)

(8) Rising Response Time

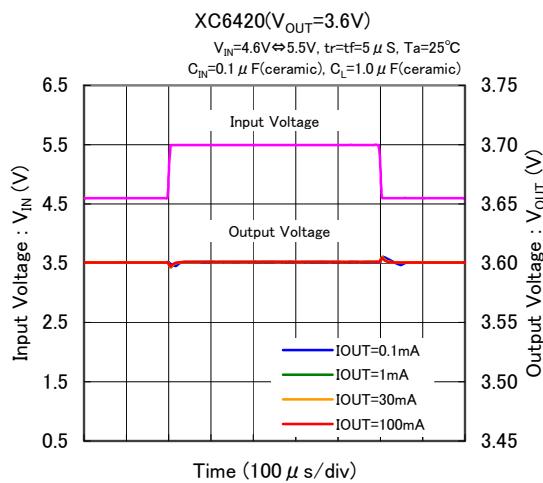
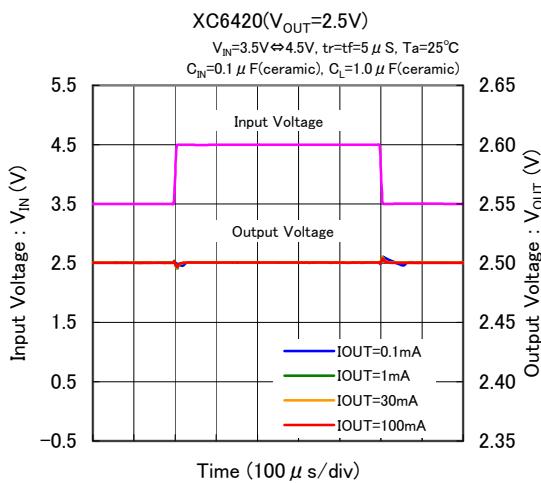


(9) Input Transient Response

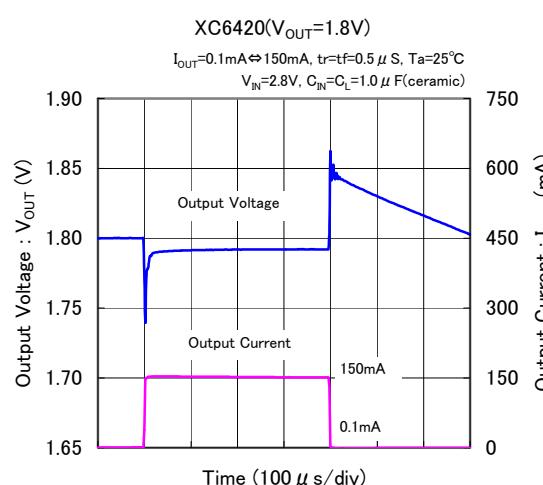
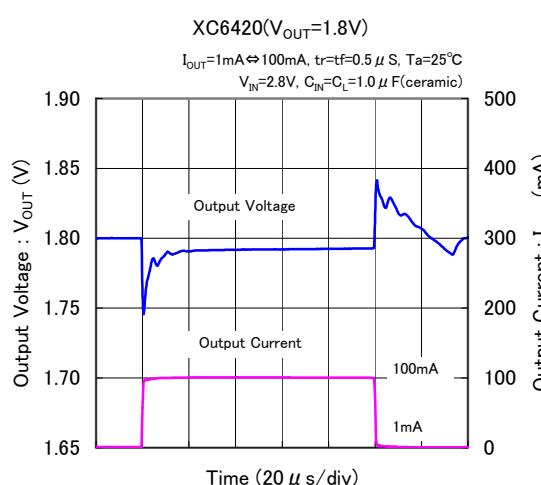
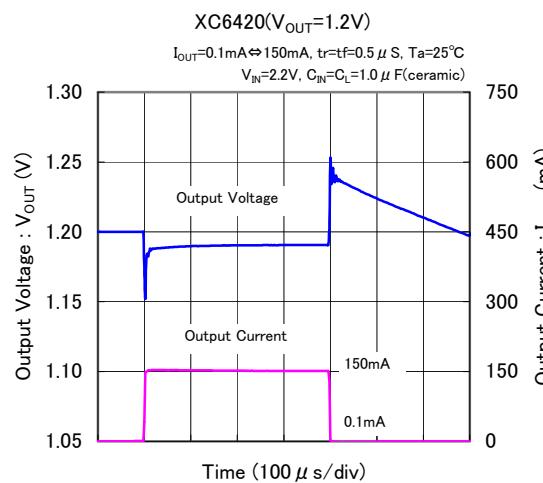
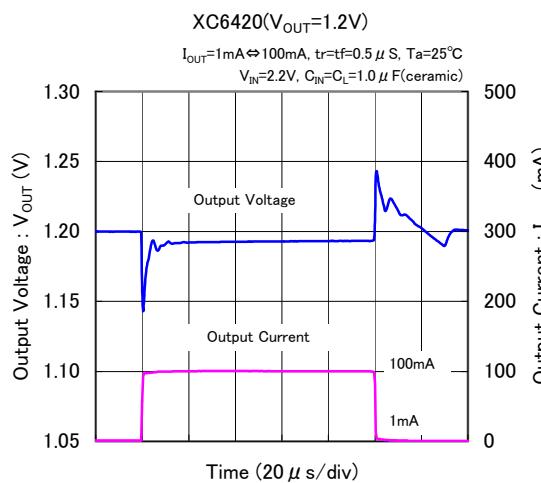


■ TYPICAL PERFORMANCE CHARACTERISTICS (Continued)

(9) Input Transient Response

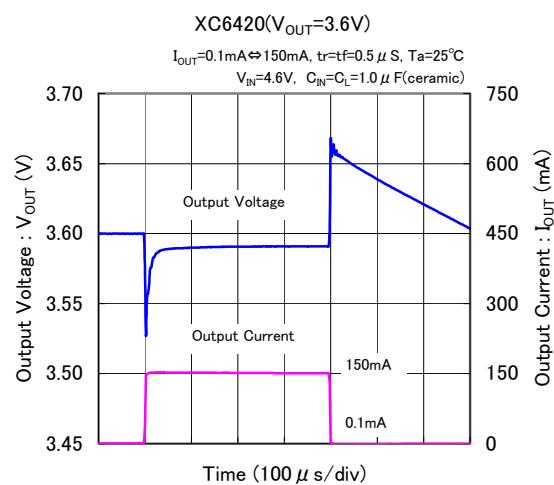
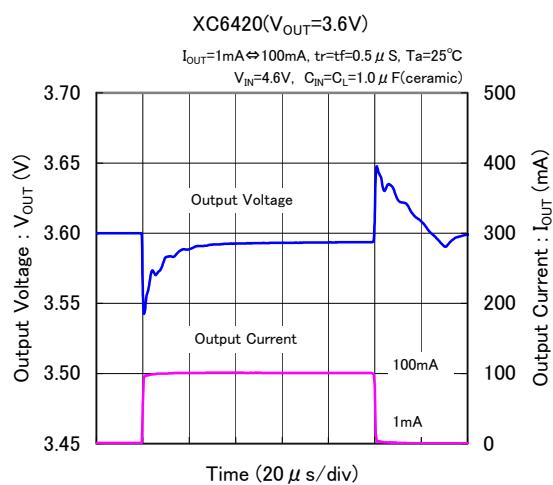
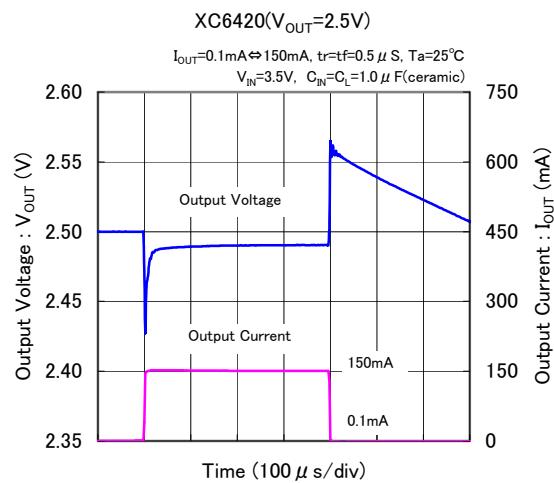
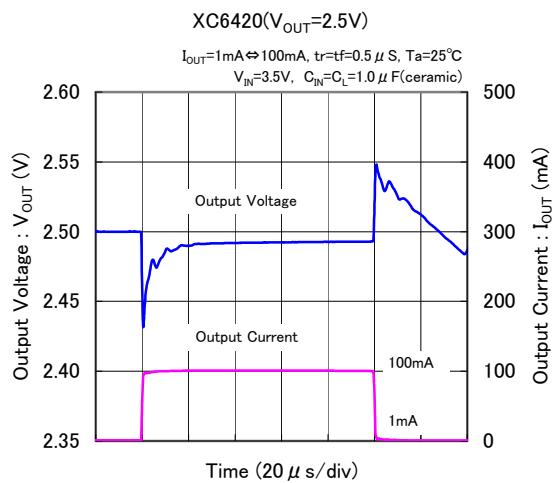


(10) Load Transient Response

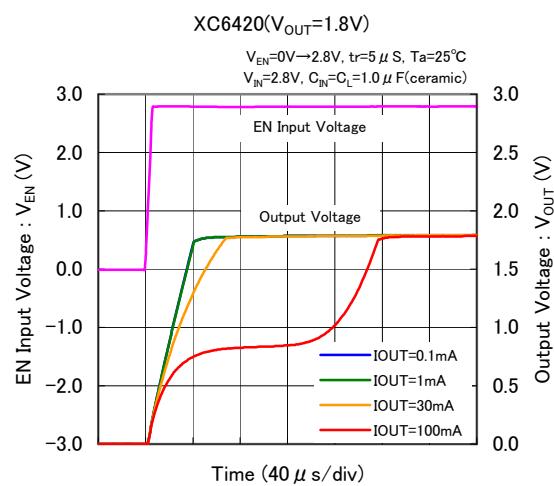
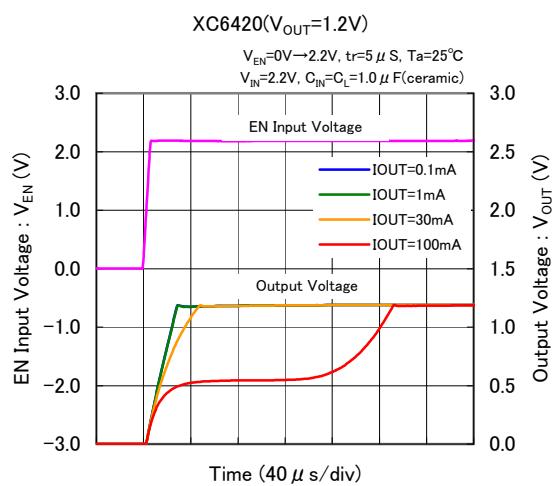


■ TYPICAL PERFORMANCE CHARACTERISTICS (Continued)

(10) Load Transient Response

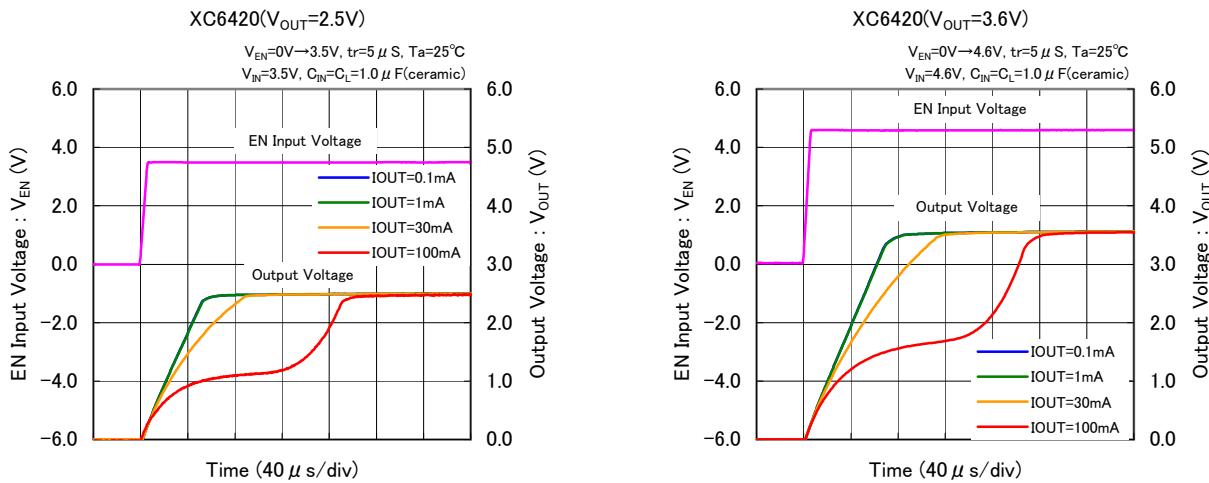


(11) EN Rising Response Time

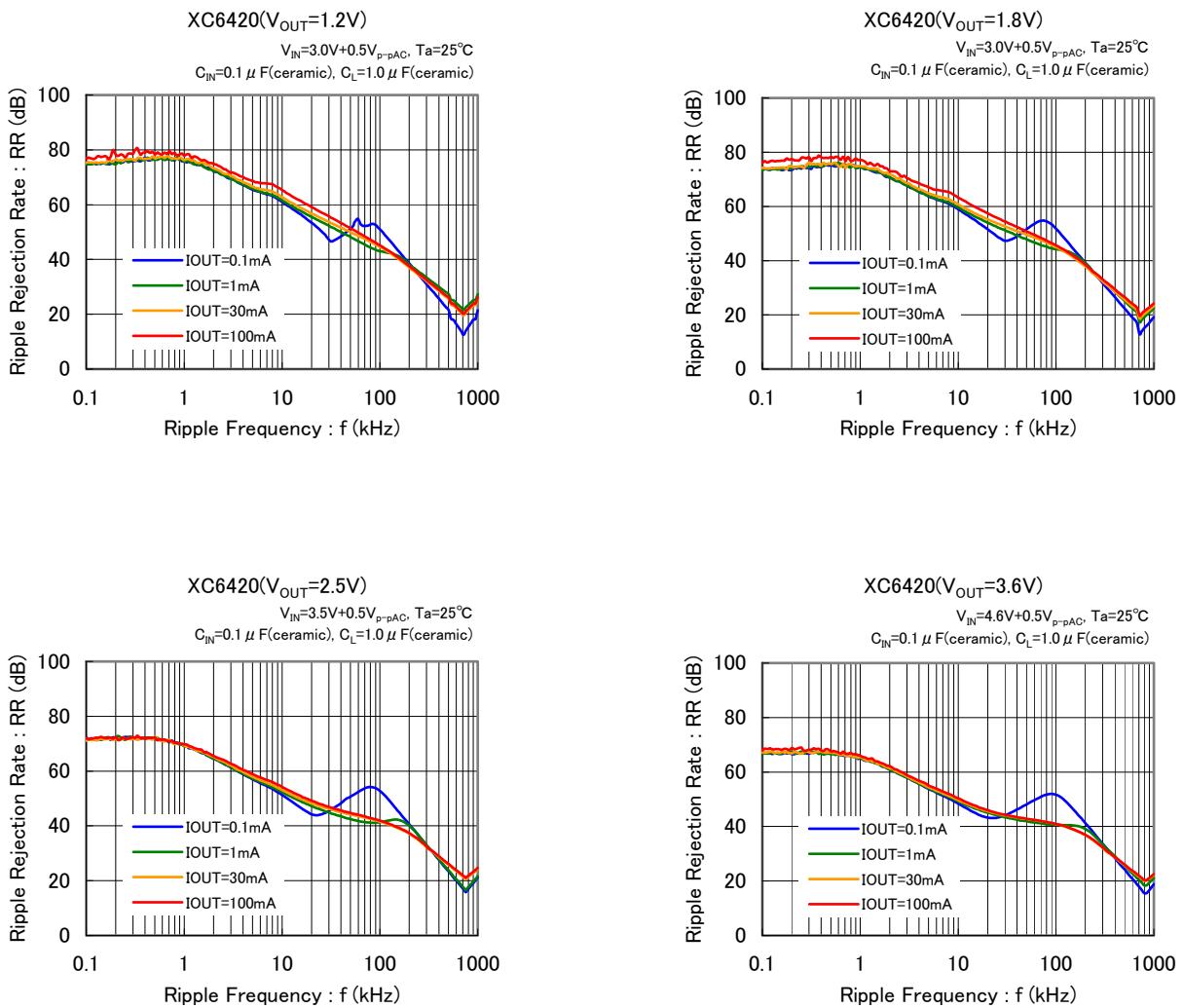


■ TYPICAL PERFORMANCE CHARACTERISTICS (Continued)

(11) EN Rising Response Time

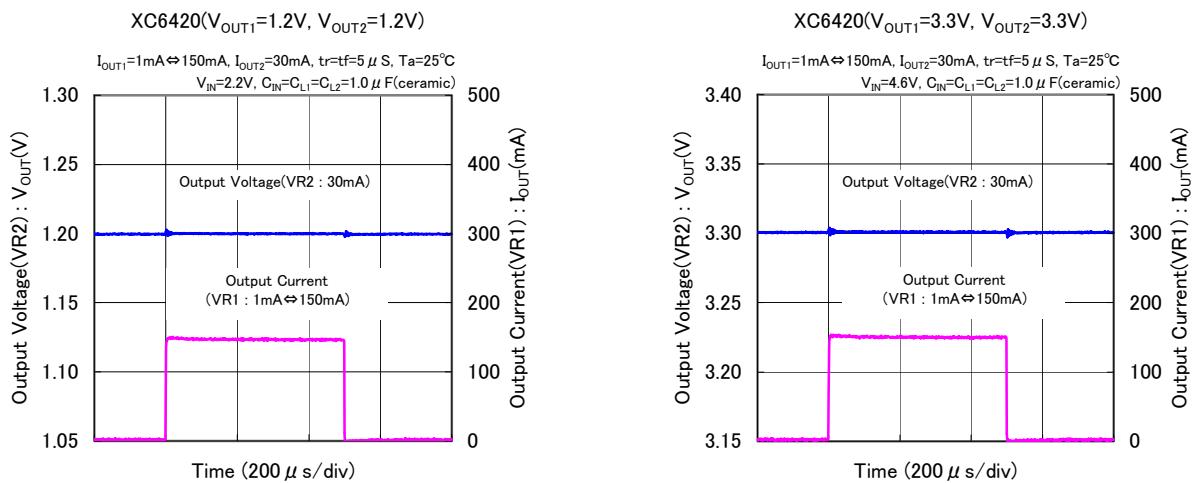


(12) Ripple Rejection

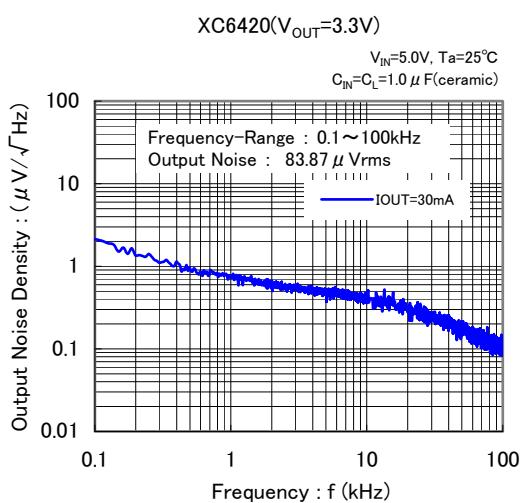
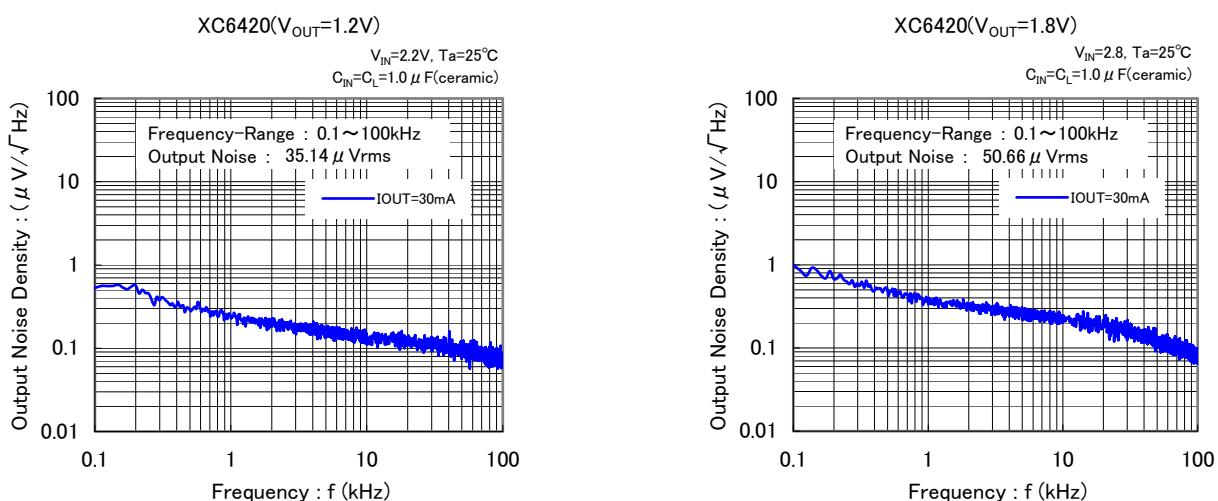


■ TYPICAL PERFORMANCE CHARACTERISTICS (Continued)

(13) Cross Talk



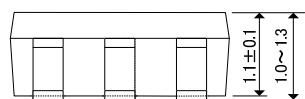
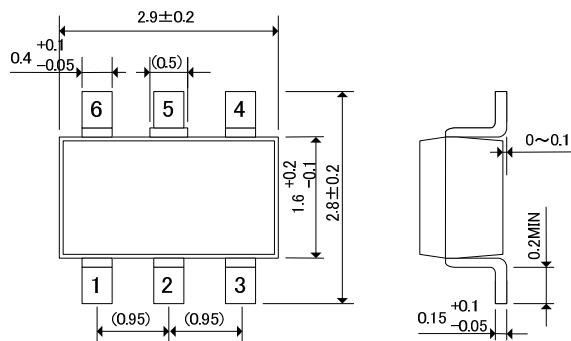
(14) Output Noise Density



■PACKAGING INFORMATION

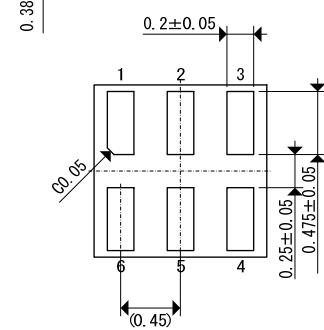
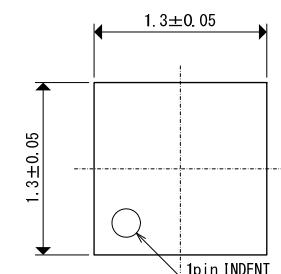
●SOT-26

(unit : mm)

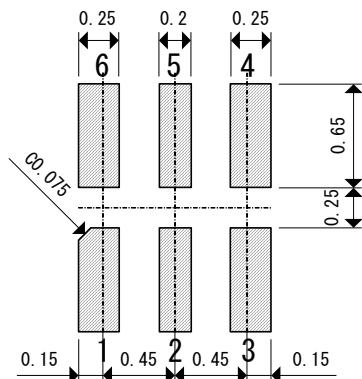


●USPN-6

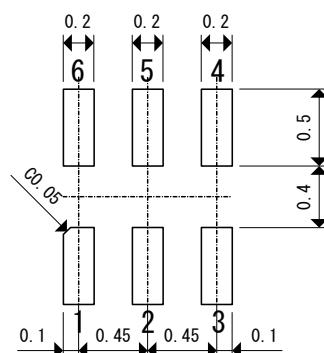
(unit : mm)



●USPN-6 Reference Pattern Layout

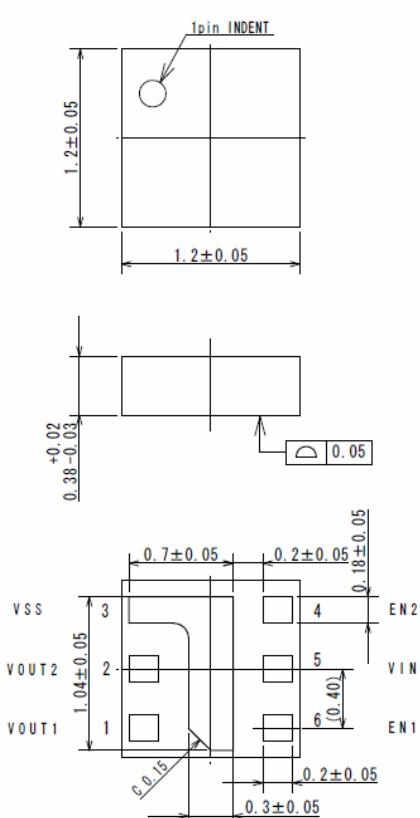


●USPN-6 Reference Metal Mask Design

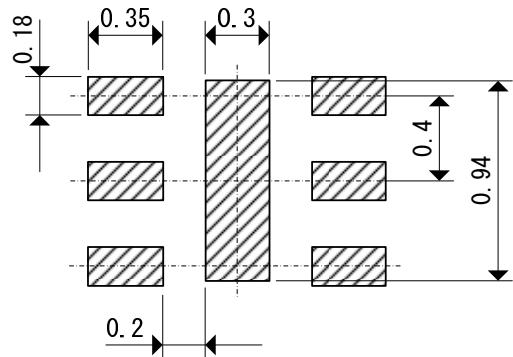


■ PACKAGING INFORMATION (Continued)

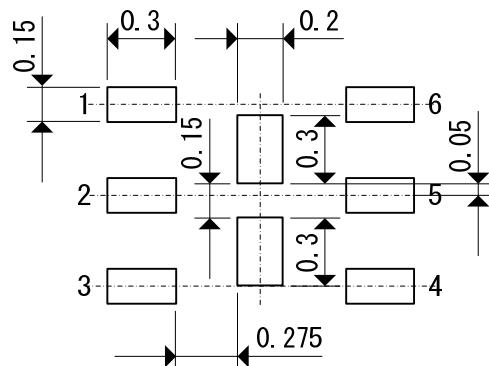
● USP-6B04



● USP-6B04 Reference Pattern Layout



● USP-6B04 Reference Metal Mask Design



■PACKAGING INFORMATION (Continued)

● SOT-26 Power Dissipation

Power dissipation data for the SOT-26 is shown in this page.

The value of power dissipation varies with the mount board conditions.

Please use this data as the reference data taken in the following condition.

1. Measurement Condition

Condition: Mount on a board

Ambient: Natural convection

Soldering: Lead (Pb) free

Board: Dimensions 40 x 40 mm (1600 mm² in one side)

Copper (Cu) traces occupy 50% of the board area

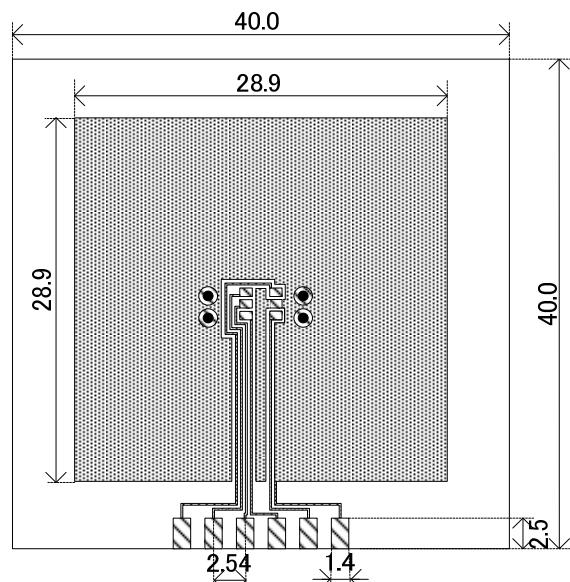
In top and back faces

Package heat-sink is tied to the copper traces

Material: Glass Epoxy (FR-4)

Thickness: 1.6 mm

Through-hole: 4 x 0.8 Diameter

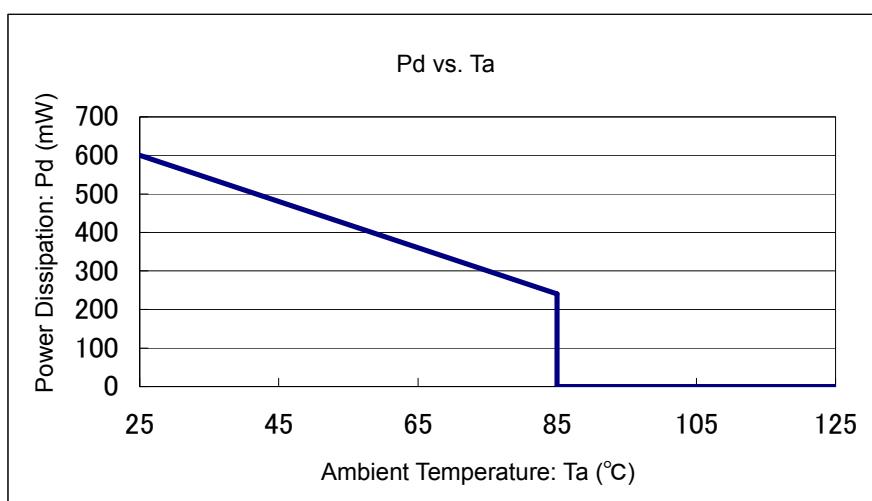


Evaluation Board (Unit: mm)

2. Power Dissipation vs. Ambient Temperature

Board Mount (T_j max = 125°C)

Ambient Temperature (°C)	Power Dissipation P_d (mW)	Thermal Resistance (°C/W)
25	600	166.67
85	240	



■ PACKAGING INFORMATION (Continued)

- USPN-6 Power Dissipation

Power dissipation data for the USPN-6 is shown in this page.

The value of power dissipation varies with the mount board conditions.

Please use this data as the reference data taken in the following condition..

1. Measurement Condition

Condition: Mount on a board

Ambient: Natural convection

Soldering: Lead (Pb) free

Board: 40 x 40 mm (1600 mm²)

4 Copper Layers

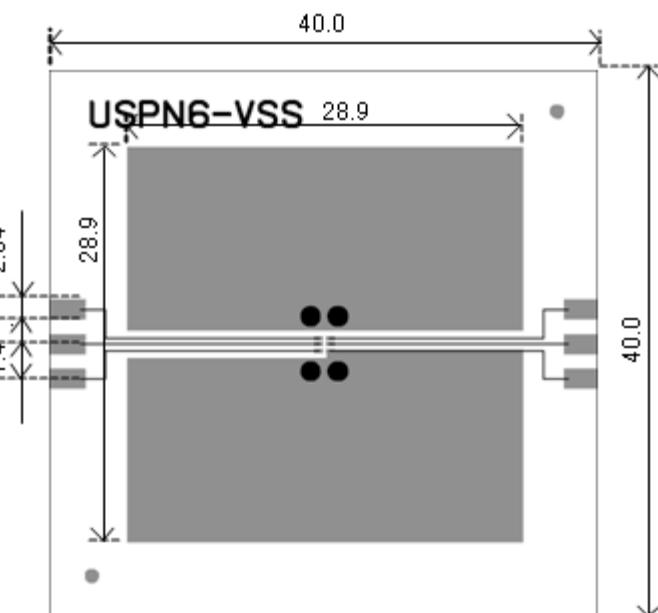
Each layer is connected to the package heat-sink
and terminal pin No.1.

Each layer has approximately 800mm² copper area.

Material: Glass Epoxy (FR-4)

Thickness: 1.6 mm

Through-hole: 4 x 0.8 Diameter

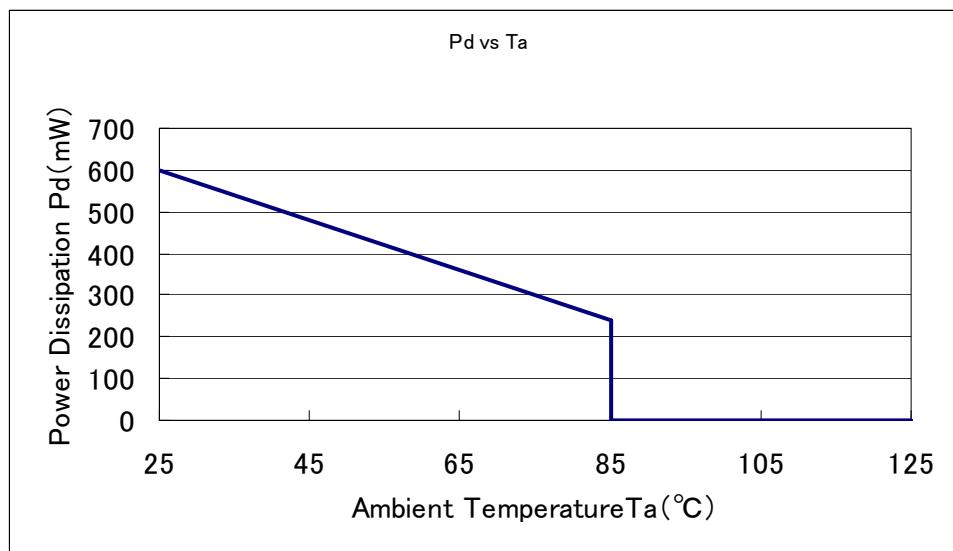


Evaluation Board (Unit: mm)

2. Power Dissipation vs. Ambient Temperature

Board Mount (T_j max = 125°C)

Ambient Temperature (°C)	Power Dissipation P_d (mW)	Thermal Resistance (°C/W)
25	600	166.67
85	240	



■PACKAGING INFORMATION (Continued)

- USP-6B04 Power Dissipation

Power dissipation data for the USP-6B04 is shown in this page.

The value of power dissipation varies with the mount board conditions.

Please use this data as the reference data taken in the following condition.

1. Measurement Condition

Condition: Mount on a board

Ambient: Natural convection

Soldering: Lead (Pb) free

Board Dimensions: 40mm×40mm (1600mm² in one side)

1st Inner Metal Layer about 50%

2nd Inner Metal Layer about 50%

3rd Inner Metal Layer about 50%

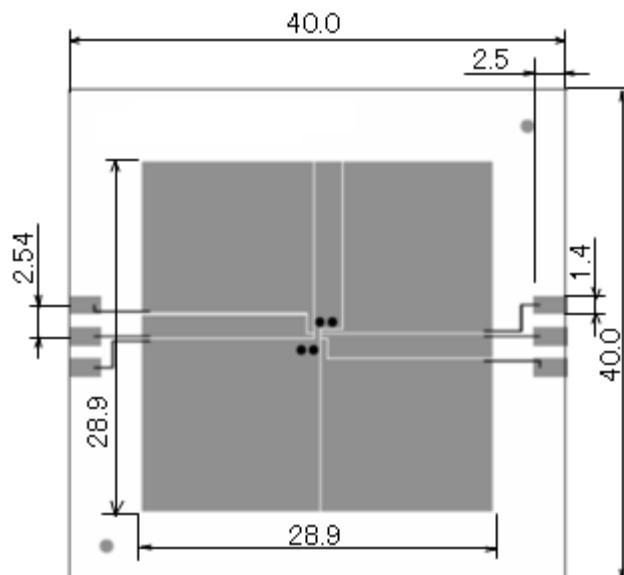
4th Inner Metal Layer about 50%

Each heat sink back metal is connected to the
Inner layers respectively.

Material: Glass Epoxy (FR-4)

Thickness: 1.0 mm

Through-hole: 4 x 0.4 Diameter

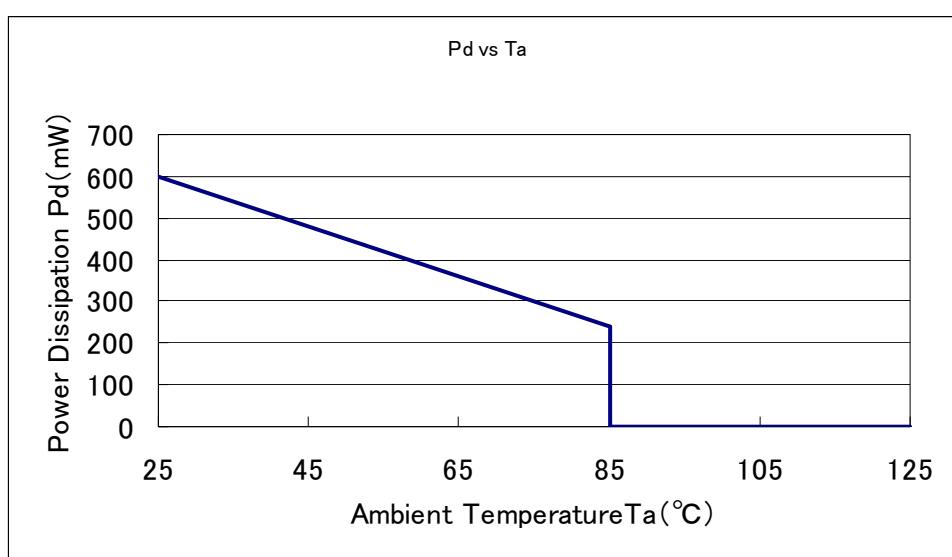


Evaluation Board (Unit: mm)

2. Power Dissipation vs. Ambient Temperature

Board Mount (T_j max = 125°C)

Ambient Temperature (°C)	Power Dissipation P_d (mW)	Thermal Resistance (°C/W)
25	600	166.67
85	240	

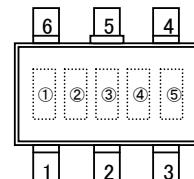


■ MARKING RULE

● SOT-26

① represents product series

MARK	PRODUCT SERIES
2	XC6420*****-G



SOT-26
(TOP VIEW)

②③ represents output voltage

ex.)

MARK		PRODUCT SERIES
②	③	
0	1	XC6420**01**-G

④⑤ represents production lot number.

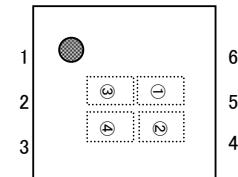
01 to 09, 0A to 0Z, 11 to 9Z, A1 to A9, AA to Z9, ZA to ZZ in order.

(G, I, J, O, Q, W excepted)

*No character inversion used.

● USPN-6/USP-6B04

①② represents internal sequential number



USPN-6/USP-6B04
(TOP VIEW)

③④ represents production lot number.

01 to 09, 0A to 0Z, 11 to 9Z, A1 to A9, AA to Z9, ZA to ZZ in order.

(G, I, J, O, Q, W excepted)

*No character inversion used.

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